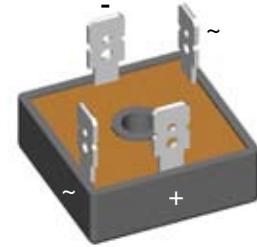
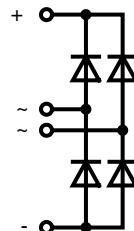


# Single Phase Rectifier Bridge

$I_{dAV} = 21 \text{ A}$   
 $V_{RRM} = 800-1800 \text{ V}$

$V_{RSM}$	$V_{RRM}$	Type
$V_{DSM}$	$V_{DRM}$	
$V$	$V$	
800	800	VBO 22-08N08
1200	1200	VBO 22-12N08
1400	1400	VBO 22-14N08
1600	1600	VBO 22-16N08
1800	1800	VBO 22-18N08



RL

Symbol	Conditions	Maximum Ratings		
$I_{dAV}$	$T_C = 85^\circ\text{C}$ , module	17	A	
$I_{dAVM}$	$T_C = 63^\circ\text{C}$ , module	21	A	
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz)	380	A	
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz)	440	A	
	$T_{VJ} = T_{VJM}$ ; $t = 10 \text{ ms}$ (50 Hz)	360	A	
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz)	400	A	
$I^2t$	$T_{VJ} = 45^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz)	725	$\text{A}^2\text{s}$	
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz)	800	$\text{A}^2\text{s}$	
	$T_{VJ} = T_{VJM}$ ; $t = 10 \text{ ms}$ (50 Hz)	650	$\text{A}^2\text{s}$	
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz)	650	$\text{A}^2\text{s}$	
$T_{VJ}$		-40...+150	$^\circ\text{C}$	
$T_{VJM}$		150	$^\circ\text{C}$	
$T_{stg}$		-40...+150	$^\circ\text{C}$	
$V_{ISOL}$	50/60 Hz, RMS $t = 1 \text{ min}$	2500	V~	
	$I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	3000	V~	
$M_d$	Mounting torque (M5) (10-32 UNF)	$2 \pm 10\%$ $18 \pm 10\%$	Nm lb.in.	
<b>Weight</b>	Typ.	22	g	

Symbol	Conditions	Characteristic Values		
$I_R$	$V_R = V_{RRM}$ $T_{VJ} = 25^\circ\text{C}$	0.3	mA	
	$T_{VJ} = T_{VJM}$	5.0	mA	
$V_F$	$I_F = 150 \text{ A}$ $T_{VJ} = 25^\circ\text{C}$	2.2	V	
$V_{TO}$	For power-loss calculations only	0.85	V	
$r_t$		12	$\text{m}\Omega$	
$R_{thJC}$	per diode; 120° el. per module	8.20 2.05	K/W	
$R_{thCH}$	per diode; 120° el. per module	9.40 2.35	K/W	
$d_s$	Creeping distance on surface	12.7	mm	
$d_A$	Creepage distance in air	9.4	mm	
$a$	Max. allowable acceleration	50	$\text{m}/\text{s}^2$	

Data according to IEC 60747 and refer to a single diode unless otherwise stated.

IXYS reserves the right to change limits, test conditions and dimensions.

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## Features

- Package with 1/4" fast-on terminals
- Isolation voltage 3000 V~
- Planar passivated chips
- Blocking voltage up to 1800 V
- Low forward voltage drop
- UL registered E 72873

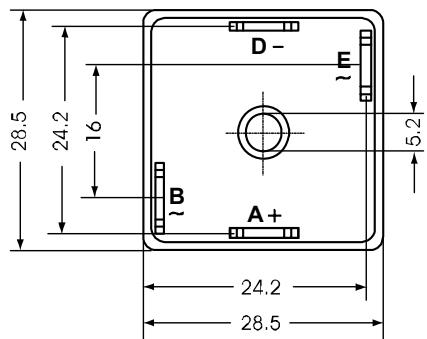
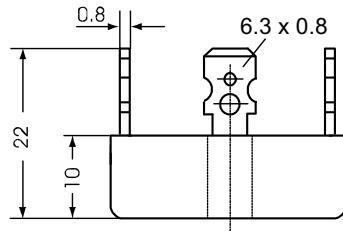
## Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

## Advantages

- Easy to mount with one screw
- Space and weight savings
- Improved temperature & power cycling

## Dimensions in mm (1 mm = 0.0394")



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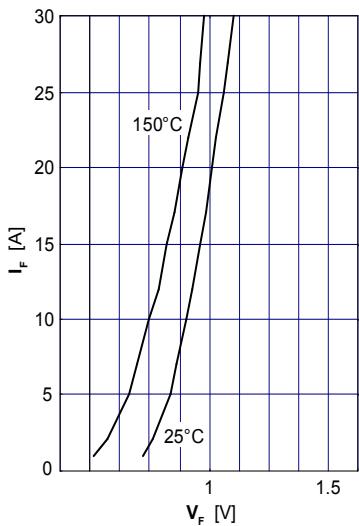


Fig. 1 Forward current versus voltage drop per diode

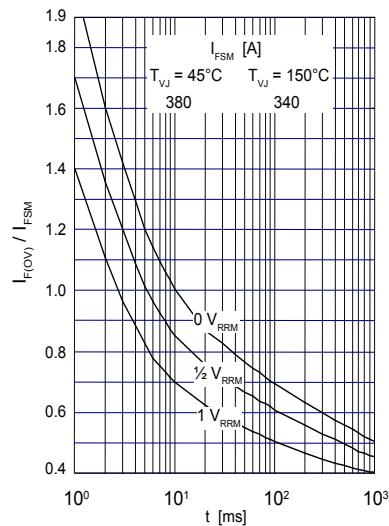


Fig. 2 Surge overload current per diode  
 $I_{FSM}$ : Crest value. t: duration

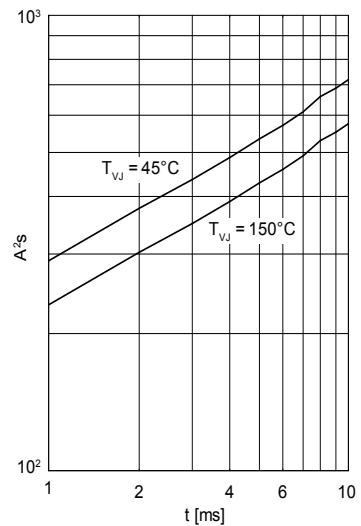


Fig. 3  $I^2t$  versus time (1-10 ms)  
per diode or thyristor

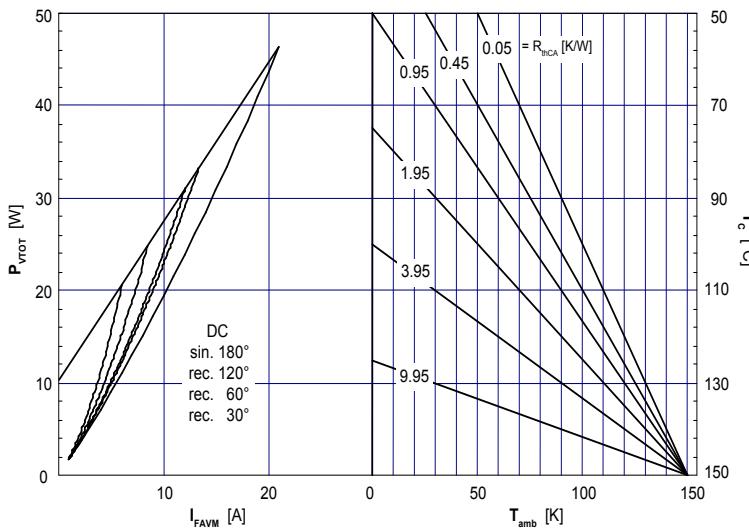


Fig. 4 Power dissipation vs. direct output current and ambient temperature

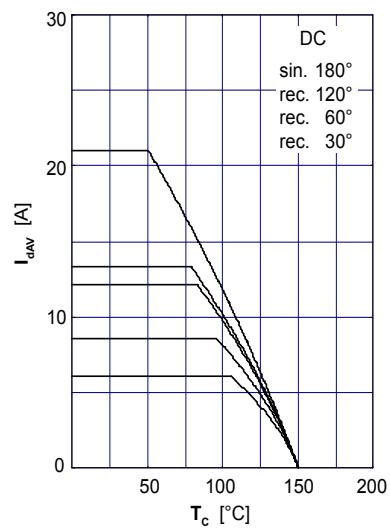


Fig. 5 Maximum forward current  
at case temperature

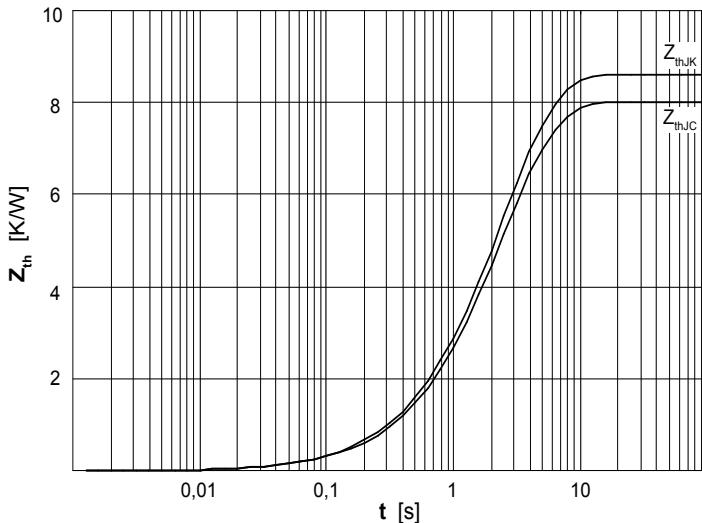


Fig. 6 Transient thermal impedance per diode or thyristor, calculated